

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Very high switching speed

Applications

- Compact fluorescent lamps (CFLs)
- SMPS for battery charger

Description

This device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA.

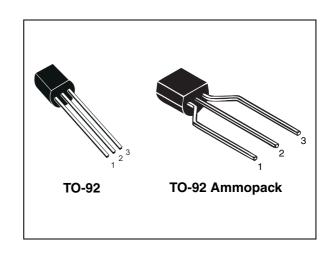


Figure 1. Internal schematic diagram

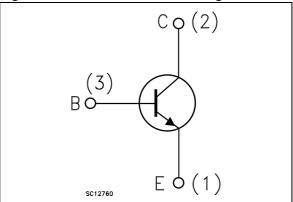


Table 1. Device summary

Order codes	codes Marking Package		Packaging	
STX0560	X0560	TO-92	Bag	
STX0560-AP	X0560	TO-92AP	Ammopack	

Electrical ratings STX0560

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	800	V	
V _{CEO}	Collector-emitter voltage (I _B = 0)	600	V	
V _{EBO}	Emitter-base voltage ($I_C = 0$)	7	V	
I _C	Collector current	1	Α	
I _{CM}	Collector peak current (t _P < 5 ms)	2	Α	
I _B	Base current	0.5	Α	
I _{BM}	Base peak current (t _P < 5 ms)	1	Α	
P _{TOT}	Total dissipation at $T_a = 25$ °C 1.5		W	
T _{stg}	Storage temperature -65 to 150		°C	
TJ	Max. operating junction temperature	150		

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJa}	Thermal resistance junction-ambient max	83	°C/W

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter Test conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 800 V			10	μΑ
V _{(BR)EBO}	Emitter-base breakdown voltage $(I_C = 0)$	I _E = 10 mA				٧
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA	600			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 0.5 \text{ A}$ $I_B = 100 \text{ mA}$			1	V
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = 0.5 \text{ A}$ $I_B = 100 \text{ mA}$			1	V
h _{FE}	DC current gain	$I_{\text{C}} = 5 \text{ mA} \qquad \qquad V_{\text{CE}} = 5 \text{ V}$ $I_{\text{C}} = 20 \text{ mA} \qquad \qquad V_{\text{CE}} = 5 \text{ V}$	70	90		
	Resistive load					
t _r	Rise time	$V_{\rm CC}$ =200 V, $I_{\rm C}$ =0.3 A		140		ns
t _s	Storage time I _{B1} =60 mA, I _{B2} =-120 mA			4.4		μs
t _f	Fall time	T _p =30 μs		220		ns

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %.

Electrical characteristics STX0560

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

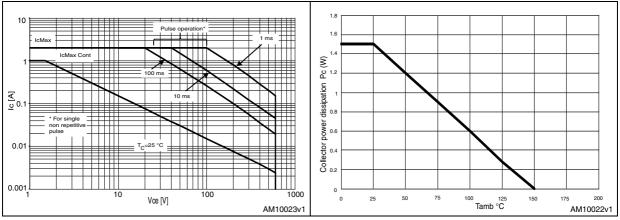


Figure 4. Output curves up to $V_{CE}=2 V$

Figure 5. Output curves up to V_{CE}=10 V

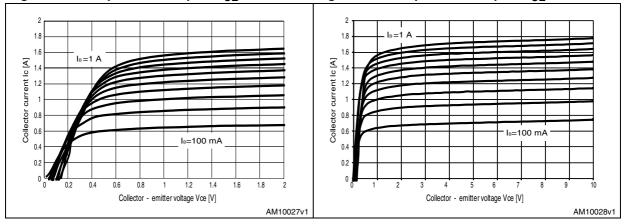
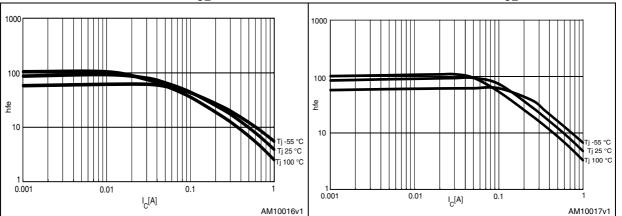


Figure 6. DC current gain $(V_{CE} = 1 V)$

Figure 7. DC current gain (V_{CE} = 5 V)



Tj -55 °C Tj 25 °C Tj 100 °C $h_{FE} = 5$ 0.8 Tj 25 °C VBE (Sat) [V] Vcesat [V] Tj -55 °C 0.4 0.2 0.001 0.01 0.01 0.1 lc[A] Ic[A] AM10018v1 AM10019v1

Figure 8. Collector-emitter saturation voltage Figure 9. **Base-emitter saturation voltage**

Figure 10. Base-emitter on voltage

1.2 Tj -55 °C Tj 25 °C Tj 100 °C 0.8 Vbe(on) [V] Vce=5 V 0.4 0.2 0.01 0.1 lc[A] AM10020v1

Figure 11. **Capacitance variation**

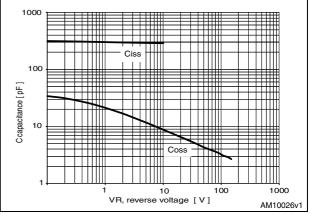


Figure 12. Resistive switching time

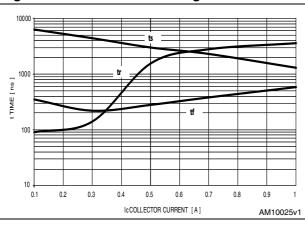
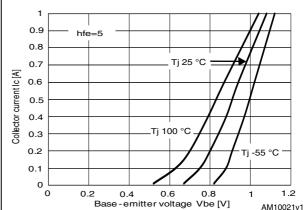
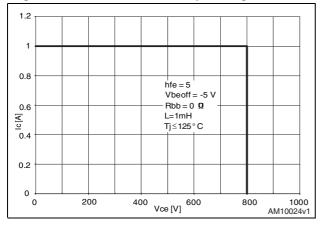


Figure 13. V_{be(sat)} vs. I_C



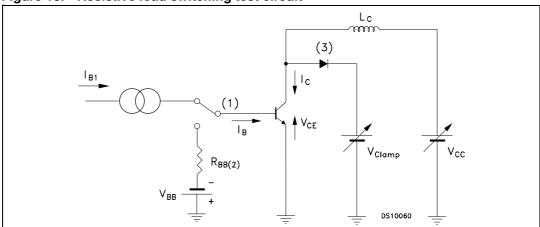
Electrical characteristics STX0560

Figure 14. Reverse biased operating area



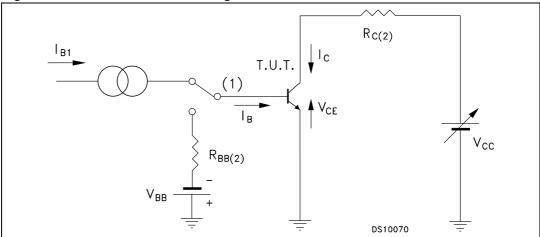
2.2 Test circuits

Figure 15. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 16. Inductive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

3 Package mechanical data

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Table 5. TO-92 mechanical data

Dim.	mm.			
	Min.	Тур.	Max.	
Α	4.32		4.95	
b	0.36		0.51	
D	4.45		4.95	
E	3.30		3.94	
е	2.41		2.67	
e1	1.14		1.40	
L	12.70		15.49	
R	2.16		2.41	
S1	0.92		1.52	
W	0.41		0.56	
V		5°		

Figure 17. TO-92 drawing

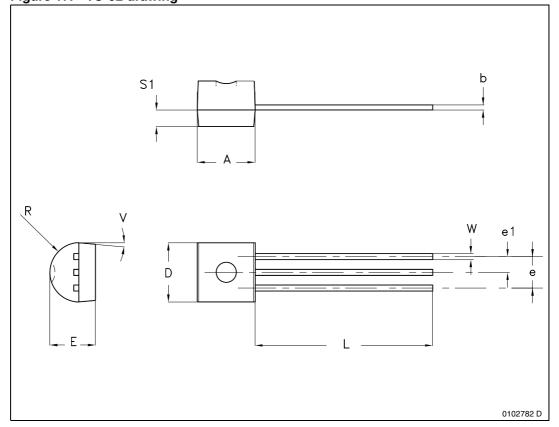


Table 6. TO-92 ammopack mechanical data

Dim	mm			
Dim.	Min.	Тур.	Max.	
A1			4.80	
Т			3.80	
T1			1.60	
T2			2.30	
d			0.48	
P0	12.50	12.70	12.90	
P2	5.65	6.35	7.05	
F1, F2	2.44	2.54	2.94	
F3	4.98	5.08	5.48	
delta H	-2.00		2.00	
W	17.50	18.00	19.00	
WO	5.70	6.00	6.30	
W1	8.50	9.00	9.25	
W2			0.50	
Н	18.50		20.50	
НЗ	0.5	1	1.5	
H0	15.50	16.00	16.50	
H1			25.00	
D0	3.80	4.00	4.20	
t			0.90	
L			11.00	
l1	3.00			
delta P	-1.00		1.00	

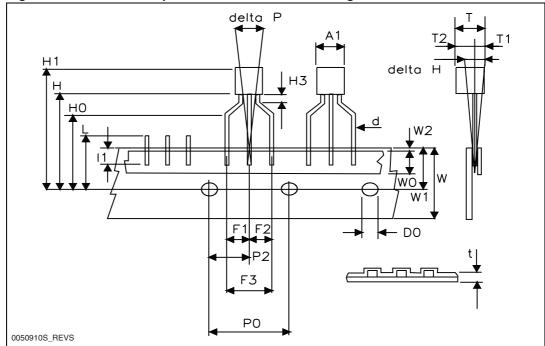


Figure 18. TO-92 ammopack mechanical data drawing

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Revision history STX0560

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
15-Dec-2010	1	Initial release.
20-Jul-2011	2	Removed: TO-92 Ammopak package
13-Feb-2012	3	Added: TO-92 Ammopak package

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